

GS2M

2.0AMPS.GLASS PASSIVATED SURFACE MOUNT RECTIFIERS

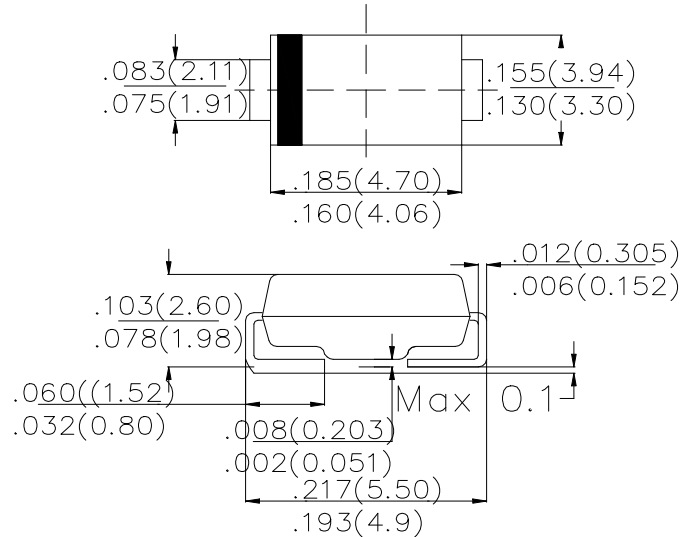
FEATURE

- . High current capability
- . Low forward voltage drop
- . Low power loss, high efficiency
- . High surge capability
- . High temperature soldering guaranteed:
260°C/10 seconds at terminals.
- . For surface mounted application.
- . Easy pick and place.

MECHANICAL DATA

- . Case: Molded plastic
- . Epoxy: UL94V-0 rate flame retardant
- . Lead: MIL-STD- 202E, Method 208 guaranteed
- . Polarity:Color band denotes cathode end
- . Packaging:12mm tape per EIA STD RS-481

SMB (DO-214AA)



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz,resistive or inductive load.For capacitive load, derate current by 20%

Type Number	SYMBOL	GS2M	units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	1000	V
Maximum RMS Voltage	V_{RMS}	700	V
Maximum DC blocking Voltage	V_{DC}	1000	V
Maximum Average Forward Rectified Current at $T_L=90^\circ\text{C}$	$I_{F(AV)}$	2.0	A
Non-repetitive forward surge current 8.3ms half sine-wave	I_{FSM}	60.0	A
Maximum Forward Voltage at 2.0 A DC	V_F	1.1	V
Maximum DC Reverse Current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	I_R	5.0 100.0	μA
Typical Junction Capacitance (Note1)	C_J	30	pF
Maximum Reverse Recovery Time (Note 2)	t_{rr}	4000	nS
Typical Thermal Resistance (Note 3)	$R_{(JA)}$	75	$^\circ\text{C}/\text{W}$
	$R_{(JC)}$	21	$^\circ\text{C}/\text{W}$
Storage Temperature	T_{STG}	-55 to +150	$^\circ\text{C}$
Operation Junction Temperature	T_J	-55 to +150	$^\circ\text{C}$

Note:

1. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
2. Reverse Recovery test Condition: $I_f=0.5\text{A}$, $I_R=1.0\text{A}$, $IRR=0.25\text{A}$
3. Measured on P.C.Board with $0.2 \times 0.2''$ ($5.0 \times 5.0\text{mm}$) Copper Pad Areas.

RATING AND CHARACTERISTIC CURVES (GS2M)

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

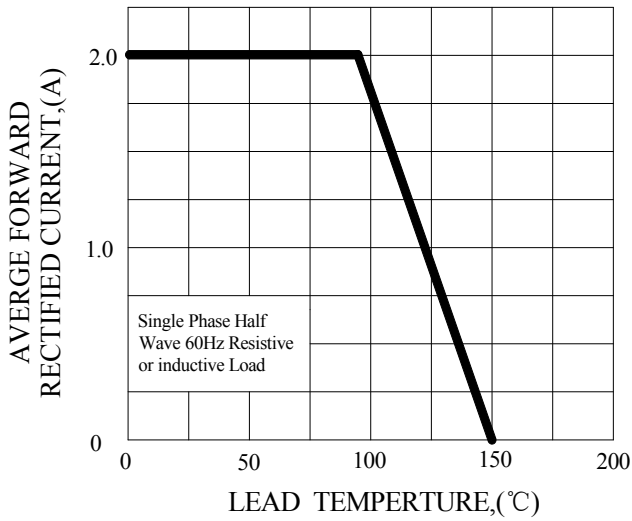


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

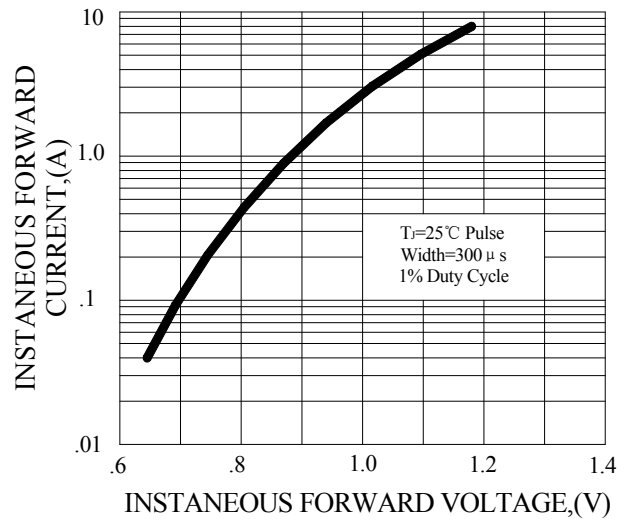


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

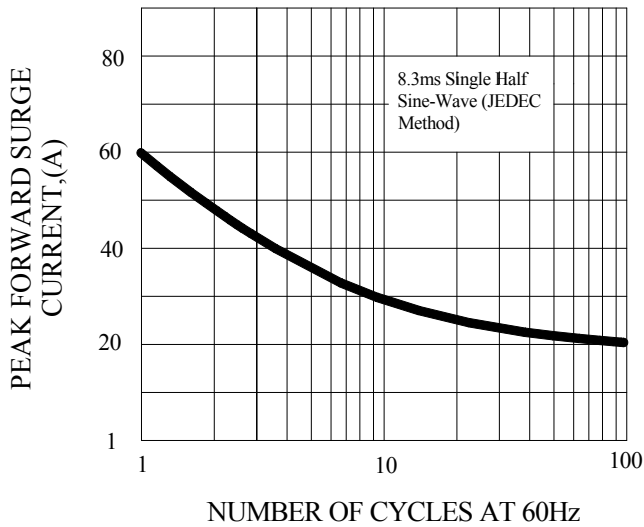


FIG.4-TYPICAL REVERSE CHARACTERISTICS

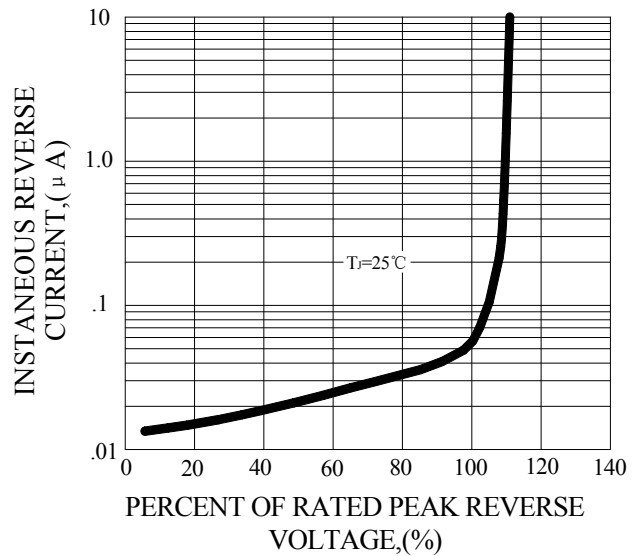
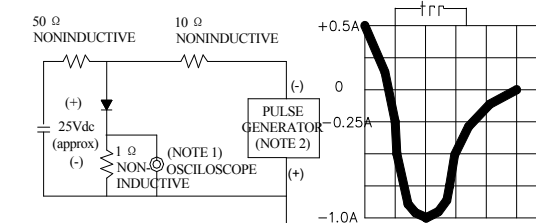


FIG.5-TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES:1. Rise Time=7ns max, Input Impedance= 1 megohm,22pF.
2. Rise Time=10ns max, Source Impedance= 50 ohms.